

## DS34LV86T 3V Enhanced CMOS Quad Differential Line Receiver

Check for Samples: [DS34LV86T](#)

### FEATURES

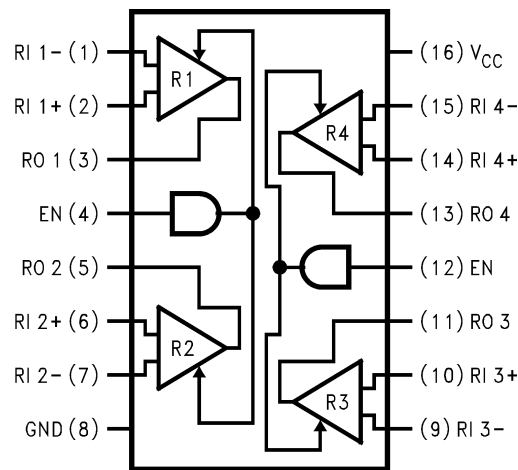
- Low Power CMOS Design (30 mW Typical)
- Interoperable With Existing 5V RS-422 Networks
- Industrial Temperature Range
- Meets TIA/EIA-422-B (RS-422) and ITU-T V.11 Recommendation
- 3.3V Operation
- $\pm 7V$  Common Mode Range @  $V_{ID} = 3V$
- $\pm 10V$  Common Mode Range @  $V_{ID} = 0.2V$
- Receiver OPEN Input Failsafe Feature
- Ensured AC Parameter:
  - Maximum Receiver Skew: 4 ns
  - Transition Time: 10 ns
- Pin Compatible With DS34C86T
- 32 MHz Toggle Frequency
- >6.5k ESD Tolerance (HBM)
- Available in SOIC Packaging

### DESCRIPTION

The DS34LV86T is a high speed quad differential CMOS receiver that meets the requirements of both TIA/EIA-422-B and ITU-T V.11. The CMOS DS34LV86T features typical low static  $I_{CC}$  of 9 mA which makes it ideal for battery powered and power conscious applications. The Tri-State enables, EN, allow the device to be disabled when not in use to minimize power consumption. The dual enable scheme allows for flexibility in turning receivers on and off.

The receiver output (RO) is ensured to be High when the inputs are left open. The receiver can detect signals as low as  $\pm 200$  mV over the common mode range of  $\pm 10V$ . The receiver outputs (RO) are compatible with TTL and LVCMOS levels.

### Connection Diagram



**Figure 1. SOIC (Top View)**  
See Package Number D



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

**TRUTH TABLE<sup>(1)</sup>**

Enable EN	Inputs RI+–RI–	Output RO
L	X	Z
H	$V_{ID} \geq +0.2V$	H
H	$V_{ID} \leq -0.2V$	L
H	Open†	H

- (1) L = Logic Low  
H = Logic High  
X = Irrelevant  
Z = Tri-State  
† = Open, Not Terminated



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

**ABSOLUTE MAXIMUM RATINGS<sup>(1)(2)</sup>**

Supply Voltage ( $V_{CC}$ )		+7V
Enable Input Voltage (EN)		+7V
Receiver Input Voltage	( $V_{ID}$ : RI+, RI–)	±14V
Receiver Input Voltage	( $V_{CM}$ : RI+, RI–)	±14V
Receiver Output Voltage (RO)		–0.5V to $V_{CC} + 0.5V$
Receiver Output Current (RO)		±25 mA
Maximum Package Power Dissipation @ +25°C	D Package	1190 mW
Derate D Package		9.8 mW/°C above +25°C
Storage Temperature Range		–65°C to +150°C
Lead Temperature Range	Soldering (4 Seconds)	+260°C
ESD Ratings (HBM, 1.5k, 100 pF)	Receiver Inputs and Enables	≥6.5 kV
	Other Pins	≥2 kV

- (1) Absolute Maximum Ratings are those values beyond which the safety of the device cannot be ensured. They are not meant to imply that the devices should be operated at these limits. The table of [Electrical Characteristics](#) specifies conditions of device operation.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.

**RECOMMENDED OPERATING CONDITIONS**

		Min	Typ	Max	Units
Supply Voltage (V <sub>CC</sub> )		3.0	3.3	3.6	V
Operating Free Air	Temperature (T <sub>A</sub> )	−40	+25	+85	°C

## ELECTRICAL CHARACTERISTICS<sup>(1)(2)</sup>

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified.

Symbol	Parameter	Conditions	Pin	Min	Typ	Max	Units
$V_{TH}$	Differential Input Threshold	$V_{OUT} = V_{OH}$ or $V_{OL}$ $-7V < V_{CM} < +7V$	RI+, RI-	-200	±17.5	+200	mV
$V_{HY}$	Hysteresis	$V_{CM} = 1.5V$			35		mV
$V_{IH}$	Minimum High Level Input Voltage		EN	2.0			V
$V_{IL}$	Minimum Low Level Input Voltage					0.8	V
$R_{IN}$	Input Resistance	$V_{IN} = -7V, +7V$ (Other Input = GND)	RI+, RI-	5.0	8.5		kΩ
$I_{IN}$	Input Current (Other Input = 0V, Power On or $V_{CC} = 0V$ )	$V_{IN} = +10V$		0	1.1	1.8	mA
		$V_{IN} = +3V$		0	0.27		mA
		$V_{IN} = 0.5V$			-0.02		mA
		$V_{IN} = -3V$		0	-0.43		mA
		$V_{IN} = -10V$		0	-1.26	-2.2	mA
$I_{EN}$		$V_{IN} = 0V$ to $V_{CC}$	EN			±1	μA
$V_{OH}$	High Level Output Voltage	$I_{OH} = -6\text{ mA}$ , $V_{ID} = +1V$ $I_{OH} = -6\text{ mA}$ , $V_{ID} = \text{OPEN}$	RO	2.4	3		V
$V_{OH}$	High Level Output Voltage	$I_{OH} = -100\text{ μA}$ , $V_{ID} = +1V$ $I_{OH} = -100\text{ μA}$ , $V_{ID} = \text{OPEN}$			$V_{CC} - 0.1$		V
$V_{OL}$	Low Level Output Voltage	$I_{OL} = +6\text{ mA}$ , $V_{ID} = -1V$			0.13	0.5	V
$I_{OZ}$	Output Tri-State Leakage Current	$V_{IN} = V_{CC}$ or GND $EN = V_{IL}$				±50	μA
$I_{SC}$	Output Short Circuit Current	$V_O = 0V$ , $V_{ID} \geq  200\text{ mV} $ See <sup>(3)</sup>		-10	-35	-70	mA
$I_{CC}$	Power Supply Current	No Load, All RI+, RI- = Open, $EN = V_{CC}$ or GND	$V_{CC}$		9	15	mA

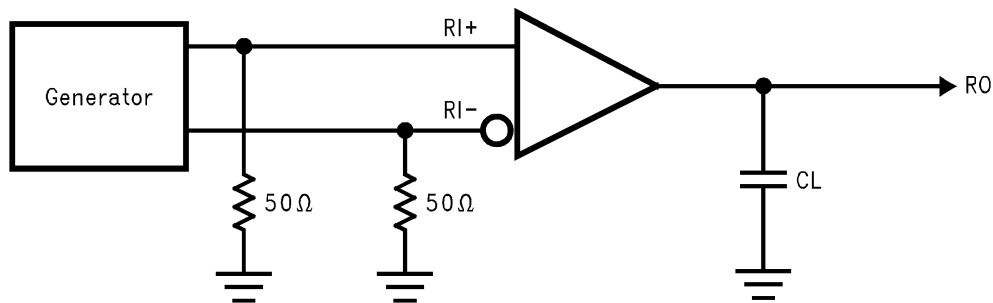
- (1) Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground except  $V_{ID}$ .
- (2) All typicals are given for:  $V_{CC} = +3.3V$ ,  $T_A = +25^\circ\text{C}$ .
- (3) Short one output at a time to ground. Do not exceed package power dissipation ratings.

**SWITCHING CHARACTERISTICS<sup>(1)(2)(3)</sup>**

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Units
$t_{PHL}$	Propagation Delay High to Low	$C_L = 15\text{ pF}$ See (Figure 2 and Figure 3 )	6	17.5	35	ns
$t_{PLH}$	Propagation Delay Low to High		6	17.8	35	ns
$t_r$	Rise Time (20% to 80%)			4.1	10	ns
$t_f$	Fall Time (80% to 20%)			3.3	10	ns
$t_{PHZ}$	Disable Time	$C_L = 50\text{ pF}$ See (Figure 4 and Figure 5)			40	ns
$t_{PLZ}$	Disable Time				40	ns
$t_{PZH}$	Enable Time				40	ns
$t_{PZL}$	Enable Time				40	ns
$t_{SK1}$	Skew, $ t_{PHL} - t_{PLH} $ See <sup>(4)</sup>	$C_L = 15\text{ pF}$		0.3	4	ns
$t_{SK2}$	Skew, Pin to Pin See <sup>(5)</sup>			0.6	4	ns
$t_{SK3}$	Skew, Part to Part See <sup>(6)</sup>			7	17	ns
$f_{MAX}$	Maximum Operating Frequency See <sup>(7)</sup>	$C_L = 15\text{ pF}$	32			MHz

- (1) All typicals are given for:  $V_{CC} = +3.3\text{V}$ ,  $T_A = +25^\circ\text{C}$ .  
 (2) Generator waveform for all tests unless otherwise specified:  $f = 1\text{ MHz}$ , Duty Cycle = 50%,  $Z_O = 50\Omega$ ,  $t_r \leq 10\text{ ns}$ ,  $t_f \leq 10\text{ ns}$ .  
 (3)  $C_L$  includes probe and jig capacitance.  
 (4)  $t_{SK1}$  is the  $|t_{PHL} - t_{PLH}|$  of a channel.  
 (5)  $t_{SK2}$  is the maximum skew between any two channels within a device, on either edge.  
 (6)  $t_{SK3}$  is the difference in propagation delay times between any channels of any devices. This specification (maximum limit) applies to devices within  $V_{CC} \pm 0.1\text{V}$  of one another, and a Delta  $T_A = \pm 5^\circ\text{C}$  (between devices) within the operating temperature range. This parameter is specified by design and characterization.  
 (7) All channels switching, output duty cycle criteria is 40%/60% measured at 50% Input = 1V to 2V, 50% Duty Cycle,  $t_r/t_f \leq 5\text{ ns}$ . This parameter is ensured by design and characterization.

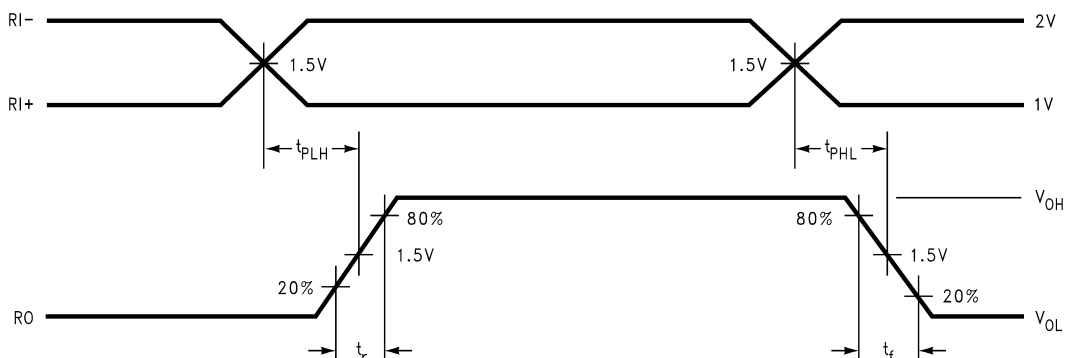
**PARAMETER MEASUREMENT INFORMATION**

Generator waveform for all tests unless otherwise specified:  $f = 1\text{ MHz}$ , Duty Cycle = 50%,  $Z_O = 50\Omega$ ,  $t_r \leq 10\text{ ns}$ ,  $t_f \leq 10\text{ ns}$ .

$C_L$  includes probe and jig capacitance.

**Figure 2. Receiver Propagation Delay and Transition Time Test Circuit**

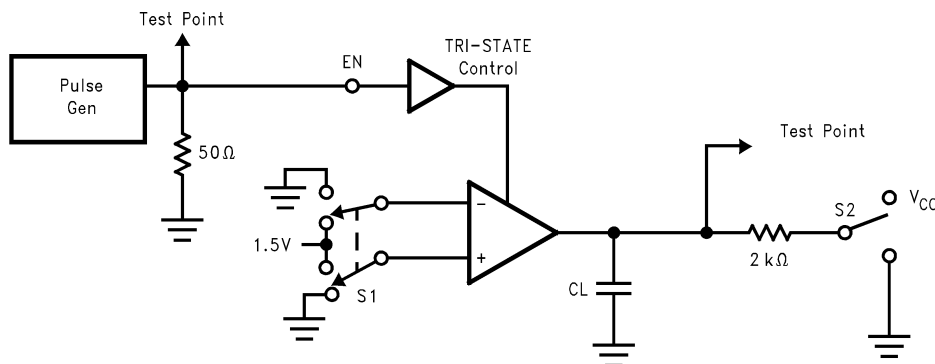
## PARAMETER MEASUREMENT INFORMATION (continued)



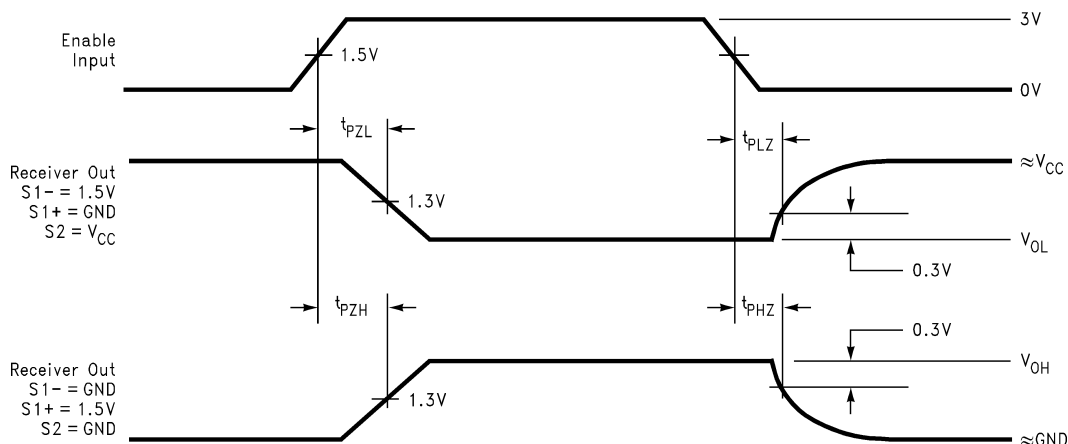
Generator waveform for all tests unless otherwise specified:  $f = 1 \text{ MHz}$ , Duty Cycle = 50%,  $Z_O = 50\Omega$ ,  $t_r \leq 10 \text{ ns}$ ,  $t_f \leq 10 \text{ ns}$ .

$C_L$  includes probe and jig capacitance.

**Figure 3. Receiver Propagation Delay and Transition Time Waveform**



**Figure 4. Receiver Tri-State Test Circuit**



Generator waveform for all tests unless otherwise specified:  $f = 1 \text{ MHz}$ , Duty Cycle = 50%,  $Z_O = 50\Omega$ ,  $t_r \leq 10 \text{ ns}$ ,  $t_f \leq 10 \text{ ns}$ .

$C_L$  includes probe and jig capacitance.

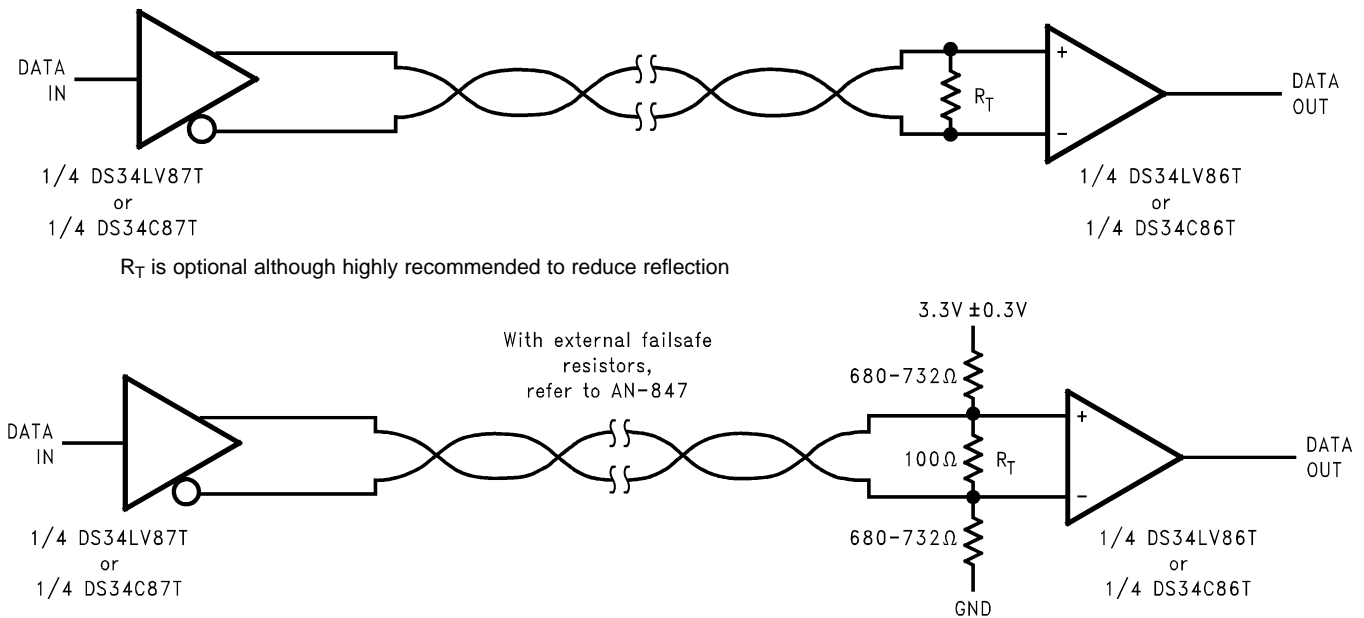
**Figure 5. Receiver Tri-State Output Enable and Disable Waveforms**

## TYPICAL APPLICATION INFORMATION

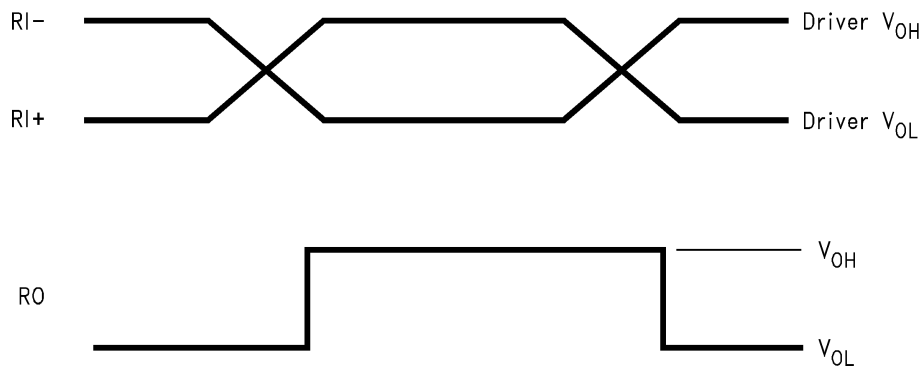
General application guidelines and hints for differential drivers receivers may be found in the following application notes:

AN-214 ([SNLA137](#)), AN-457 ([SNLA148](#)), AN-805 ([SNOA233](#)), AN-847 ([SNLA031](#)), AN-903 ([SNLA034](#)), AN-912 ([SNLA036](#)), AN-916 ([SNLA219](#))

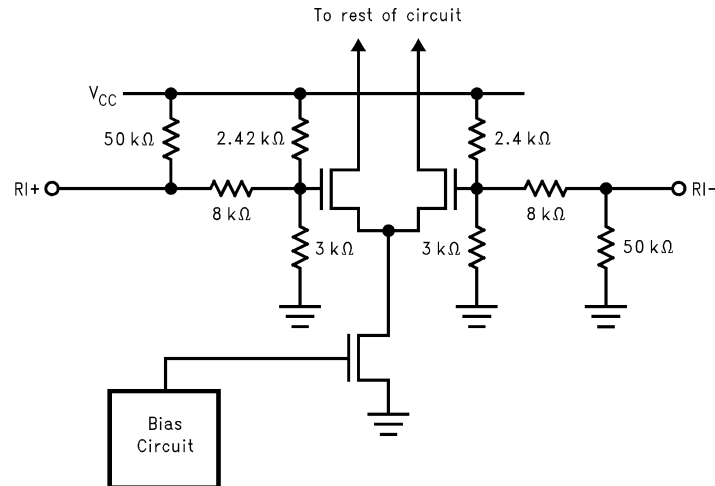
**Power Decoupling Recommendations:** Bypass caps must be used on power pins. High frequency ceramic (surface mount is recommended) 0.1  $\mu\text{F}$  in parallel with 0.01  $\mu\text{F}$  at the power supply pin. A 10  $\mu\text{F}$  or greater solid tantalum or electrolytic should be connected at the power entry point on the printed circuit board.



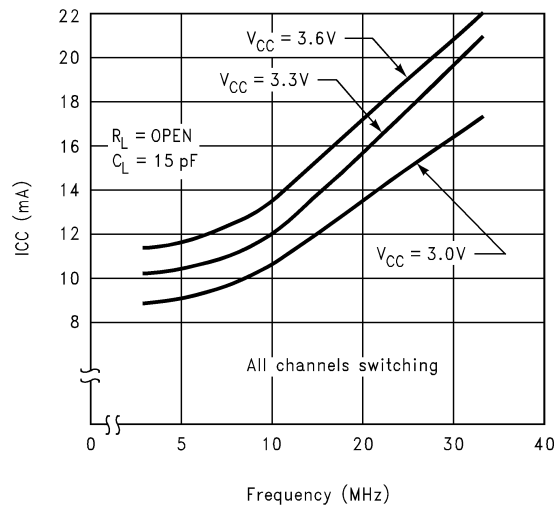
**Figure 6. Typical Receiver Connections**



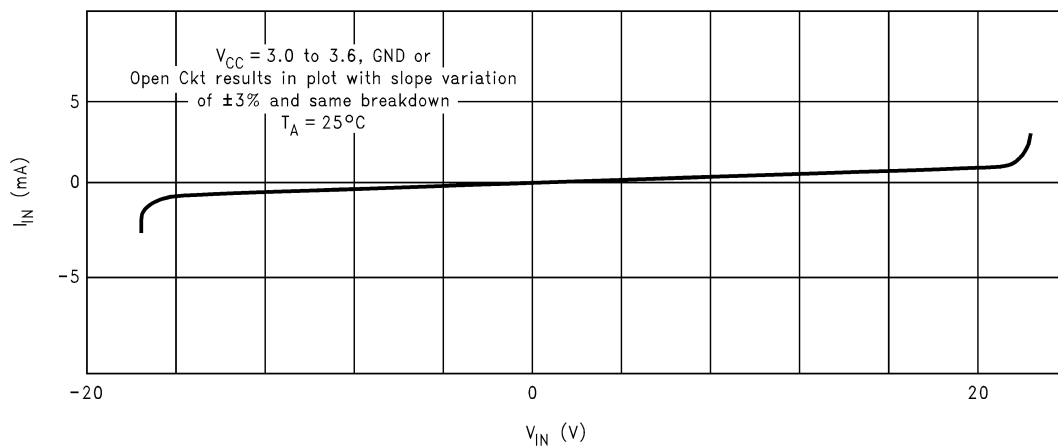
**Figure 7. Typical Receiver Output Waveforms**



**Figure 8. Typical Receiver Input Circuit**



**Figure 9. Typical  $I_{CC}$  vs Frequency**



**Figure 10.  $I_{IN}$  vs  $V_{IN}$  (Power On, Power Off)**

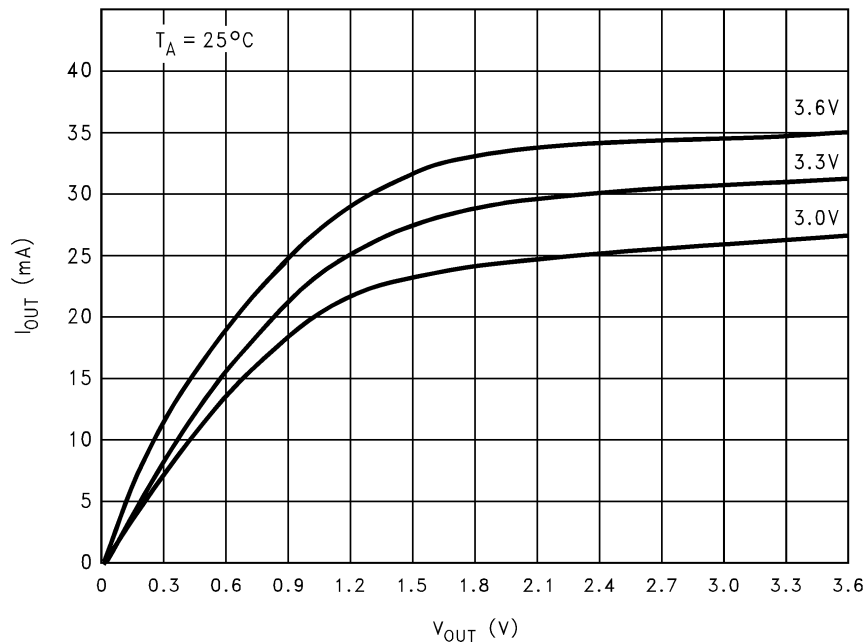


Figure 11.  $I_{OL}$  vs  $V_{OL}$

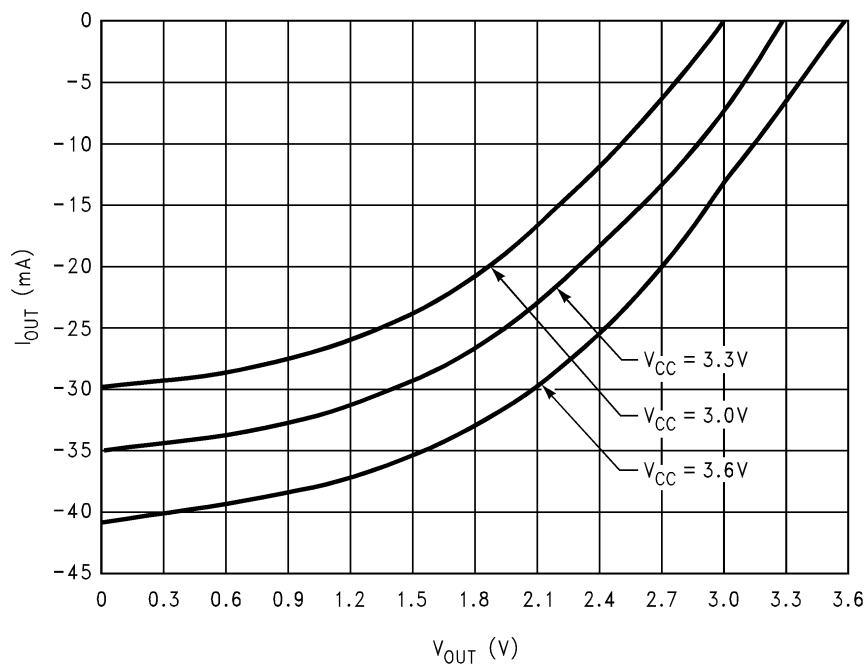


Figure 12.  $I_{OH}$  vs  $V_{OH}$



## REVISION HISTORY

### Changes from Revision C (April 2013) to Revision D

**Page**

- Changed layout of National Data Sheet to TI format ..... [8](#)

## PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">DS34LV86TM/NOPB</a>	Active	Production	SOIC (D)   16	48   TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 85	DS34LV86 TM
DS34LV86TM/NOPB.A	Active	Production	SOIC (D)   16	48   TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 85	DS34LV86 TM
<a href="#">DS34LV86TMX/NOPB</a>	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	DS34LV86 TM
DS34LV86TMX/NOPB.A	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	DS34LV86 TM

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



## TAPE AND REEL INFORMATION



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DS34LV86TMX/NOPB	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.3	8.0	16.0	Q1

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DS34LV86TMX/NOPB	SOIC	D	16	2500	367.0	367.0	35.0

## TUBE

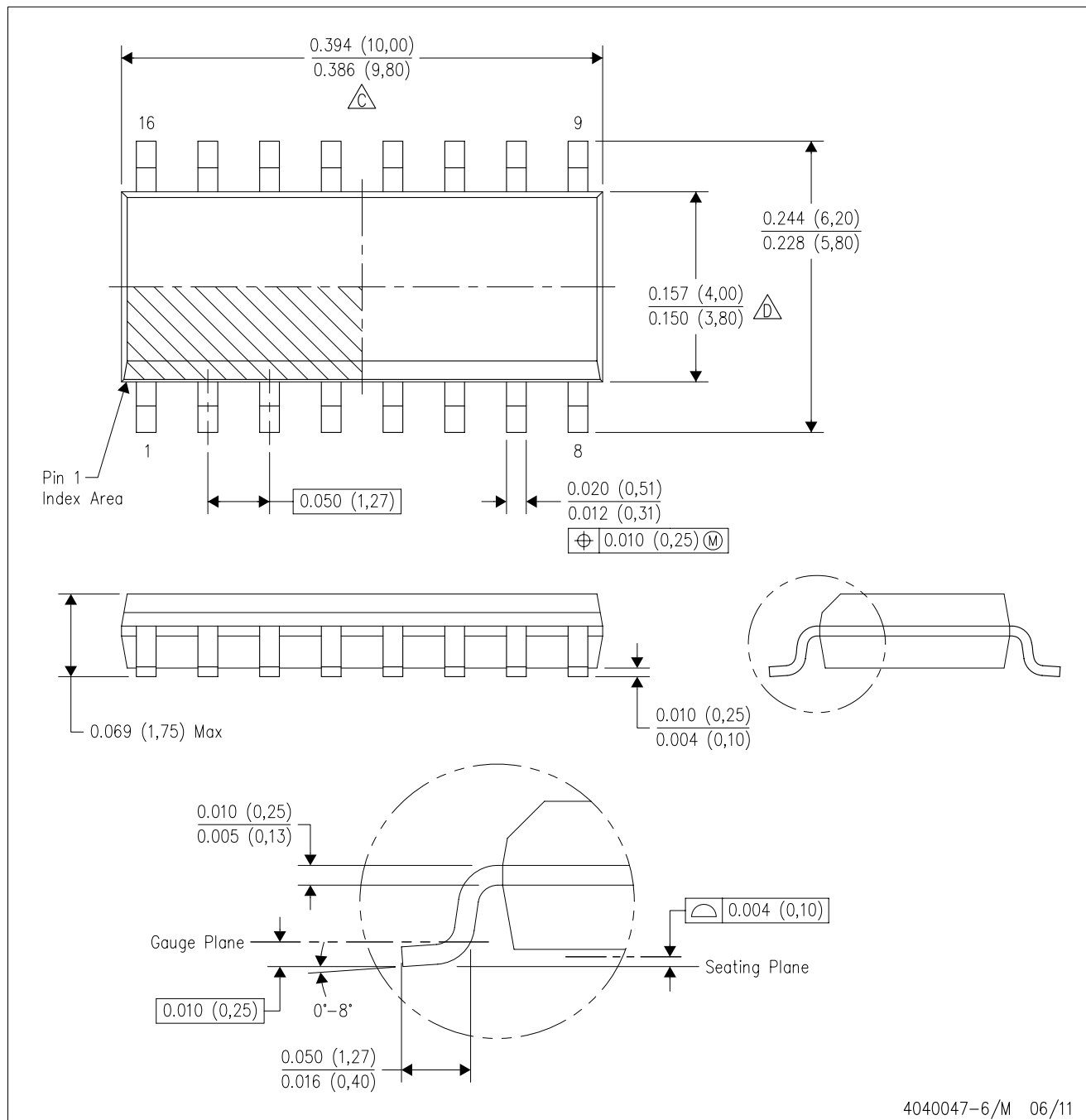


\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
DS34LV86TM/NOPB	D	SOIC	16	48	495	8	4064	3.05
DS34LV86TM/NOPB.A	D	SOIC	16	48	495	8	4064	3.05

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



4040047-6/M 06/11

- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
  - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
  - E. Reference JEDEC MS-012 variation AC.

## IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#), [TI's General Quality Guidelines](#), or other applicable terms available either on [ti.com](#) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2025, Texas Instruments Incorporated

Last updated 10/2025